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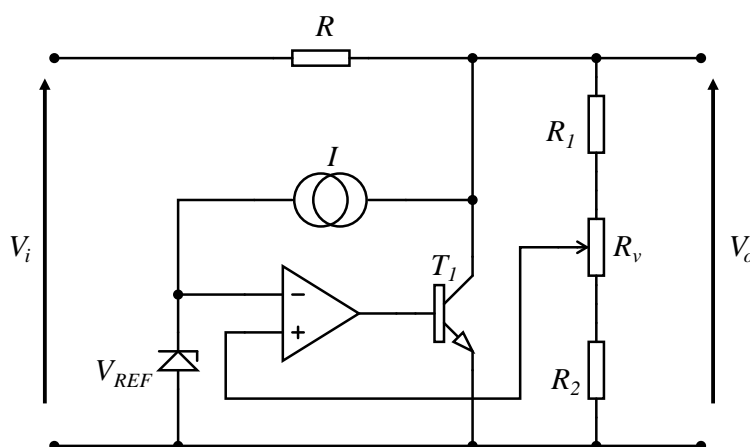
## DEPARTMENT OF ELECTRONIC AND ELECTRICAL ENGINEERING

Autumn Semester 2010-2011 (2 hours)

### EEE340 Analogue and Switching Circuits 3

Answer **THREE** questions. **No marks will be awarded for solutions to a fourth question.** Solutions will be considered in the order that they are presented in the answer book. Trial answers will be ignored if they are clearly crossed out. **The numbers given after each section of a question indicate the relative weighting of that section.**

1. The circuit shown in Figure 1 is an adjustable linear shunt regulator. It is to be used to supply a load current which may vary between 0 and 40mA. For the circuit to maintain correct operation the current through  $T_I$  must be always greater than 10mA. You may neglect the power dissipated in the voltage divider network,  $T_I$ ,  $I$ ,  $V_{REF}$  and the operational amplifier. The component values for the circuit are given in Table I.



|           |               |
|-----------|---------------|
| $V_i$     | 18V to 25V    |
| $V_{REF}$ | 3.3V          |
| $R_I$     | 10k $\Omega$  |
| $R_v$     | 4.7k $\Omega$ |
| $R_2$     | 4.7k $\Omega$ |

Table I

Figure 1

- What range of output voltage,  $V_o$ , is available by adjusting  $R_v$ ? (4)
- What is the maximum value of  $R$  that will ensure correct operation of the circuit over the full range of output voltage, load current and supply voltage conditions? (3)
- What power is dissipated by  $R$  under the worst case normal operating condition and with a prolonged short circuit across the output? (4)
- What maximum power must  $T_I$  be capable of dissipating? (4)
- What is the efficiency of the shunt regulator if the input voltage is set to 20V, output voltage is set to 10V and applied to a 500 $\Omega$  load resistor? You may neglect the power dissipated in the voltage divider network,  $T_I$ ,  $I$ ,  $V_{REF}$  and the operational amplifier. (5)

2. a. Explain why hysteresis is usually necessary in comparator circuits. Provide an example where hysteresis might be used. (2)
- b. Sketch the transfer characteristic,  $V_O$  against  $V_I$ , of the Schmitt trigger circuit shown in Figure 2a, highlighting the area of hysteresis.

Determine the two input voltage values required at  $V_I$  to achieve Low-High and High-Low switching transitions. You may assume that the voltage across the zener diode clamp is either  $V_{OH}$  or  $V_{OL}$  where  $V_{OH} = -V_{OL}$ . Determine the circuit's hysteresis in terms of  $V_{OH}$ ,  $V_{OL}$ ,  $R_1$  and  $R_2$ .

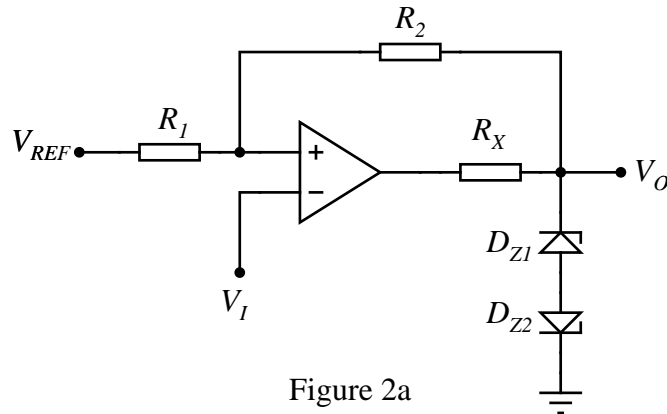


Figure 2a

(5)

The circuit presented in Figure 2a is now modified to form a triangle/square waveform oscillator as shown in Figure 2b.

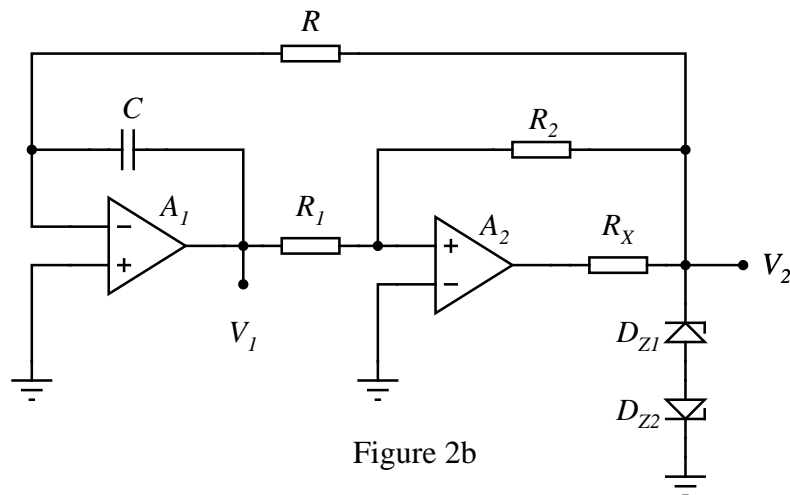


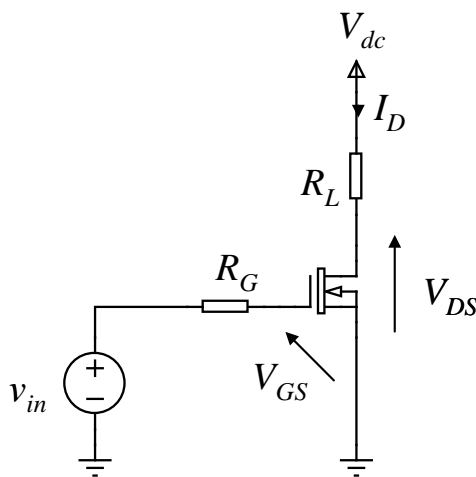
Figure 2b

- c. Sketch the waveforms one would expect to observe at the inverting integrator output ( $V_I$ ) and the Schmitt trigger output ( $V_2$ ). Label the key points on your sketch including the triangle waveform gradient. (6)
- d. Derive an expression for the period of oscillation in terms of  $R$ ,  $C$ ,  $R_1$  and  $R_2$ . You may assume that the voltage across the zener diode clamp is either  $V_{OH}$  or  $V_{OL}$  where  $V_{OH} = -V_{OL}$ .

If  $R_1 = R_2 = 4.7\text{k}\Omega$  calculate the  $RC$  product required to produce an oscillation frequency of 4kHz. (5)

- e. What is the purpose of  $R_X$  in figure 2a? (2)

3. a. Sketch a diagram of the  $V_{DS}$ - $I_D$  output characteristic for a typical N channel MOSFET showing the influence of  $V_{GS}$  on the characteristic. On your diagram label the idealised and the practical 'on' and 'off' state operating points and illustrate the linear and saturation operating regions. (5)
- b. Sketch the switching waveforms of  $V_{DS}$ ,  $I_D$  and  $V_{GS}$  as a function of time for the circuit shown in Figure 3a. Assume that  $v_{in}$  is a pulse that is long in duration in comparison with the time constants of the MOSFET, and large enough in amplitude to ensure proper on-state operation. On your diagram label the following events, turn-on and turn-off delay times, the turn-on and turn-off switching times and the on-time. (6)



|              |       |
|--------------|-------|
| $V_{dc}$     | 60V   |
| $R_L$        | 5Ω    |
| $R_G$        | 180Ω  |
| $C_{DG}$     | 33pF  |
| $C_{GS}$     | 100pF |
| $r_{DS(on)}$ | 0.2Ω  |
| $V_{TH}$     | 4V    |
| $v_{in}$     | 0□9V  |

Table III

Figure 3a

- c. For the circuit shown in Figure 3a and using the parameters shown in table III, determine the turn-on delay time and the turn-on switching time. (5)
- d. To accelerate the turn-off process, the circuit in Figure 3a is modified by connecting a series diode-resistor network in parallel with  $R_G$  as illustrated in Figure 3b. Assuming the diode has ideal characteristics (i.e. negligible forward voltage drop while conducting), what is the turn-off delay time and the turn-off switching time. (4)

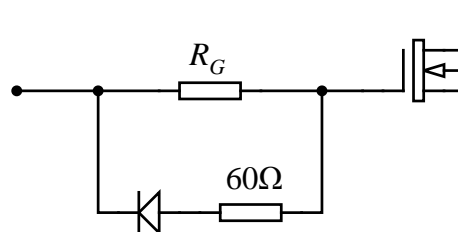


Figure 3b

4. The circuit shown in Figure 4 is a speed controller for a permanent magnet brushed DC motor. Its operating characteristics are very similar to a “buck” step-down converter in that transistor  $T_I$  is turned-on at a fixed interval (i.e. turned-on with constant switching frequency) and the speed of the motor  $\omega$  is controlled by varying the on-time of  $T_I$ . The back-emf of the motor  $E$  is proportional to speed ( $E=\psi\omega$ ) and the average current  $I$  drawn by the motor is proportional to the motor shaft torque ( $T_m=\psi I$ ). The inductor  $L$  represents the motor armature inductance. It is assumed that current continuously flows into the motor.

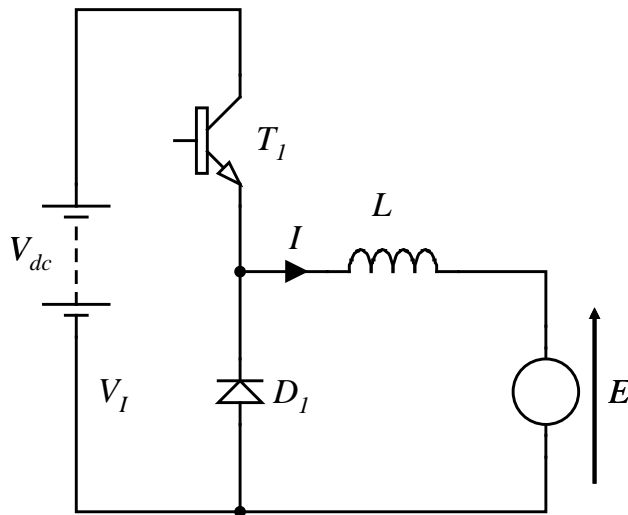


Figure 4

|                             |           |
|-----------------------------|-----------|
| $V_{dc}$                    | 40V       |
| $L$                         | 3.4mH     |
| $\psi$                      | 0.071Nm/A |
| $T_I$ on-state voltage drop | = 0.5V    |
| $D_I$ on-state voltage drop | = 1V      |

Table IV

To convert RPM to  $\text{rads}^{-1}$  use

$$\omega = \frac{2\pi}{60} \times \text{RPM}$$

- a. Draw the sub-circuits that represent the circuit behaviour when  $T_I$  is turned “on” and when  $T_I$  is turned “off” using voltage sources to represent the on-state voltage drop of the semiconductor devices. Indicate the path of current flow on your diagrams. (5)
- b. Using the values specified in Table IV and assuming the transistor  $T_I$  is turned “on” every 0.5ms, determine the required “on” time if the motor is to operate at 2000rpm. (8)

Sketch the voltage across  $D_I$ ,  $V_{DI}$ , that you would expect to observe if this circuit is operated for the conditions listed in Table IV. Label peak values of the voltage levels and the time durations for the various parts of the waveform. Your waveform should show at least one complete switching period. (8)

- c. A torque of 0.15Nm is applied to the motor shaft. Determine the average current required by the motor and the maximum and minimum current that occur due to the repetitive switching nature of the circuit for the conditions used in part b. (4)
- d. If the motor is to be operated at a minimum speed of 1000rpm, what is the minimum operating frequency that may be used that will limit the motor ripple current to 0.5A? You may neglect all transistor and diode forward voltage drops. (3)

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